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Ohshita et al.(10) **Pub. No.: US 2004/0090401 A1**(43) **Pub. Date: May 13, 2004**(54) **ORGANIC EL DISPLAY DEVICE AND
METHOD FOR MANUFACTURING THE
SAME**(30) **Foreign Application Priority Data**

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Publication Classification(51) **Int. Cl.⁷** **G09G 3/30**(52) **U.S. Cl.** **345/76**(75) **Inventors:** **Isamu Ohshita**, Yamagata-ken (JP);
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PLLC****Suite 600****1050 Connecticut Avenue, N.W.****Washington, DC 20036-5339 (US)**(73) **Assignee:** **Tohoku Pioneer Corporation**(21) **Appl. No.:** **10/701,439**(22) **Filed:** **Nov. 6, 2003**(57) **ABSTRACT**

There is provided an organic EL display device comprising: an underlying layer, including at least one layer formed of organic materials, formed on a substrate; organic EL elements formed thereon; and each leading electrode from the organic EL element for an electrical interconnection to an electrode of an interconnection object. In the display device, each connecting region is formed by removing the layers formed of organic materials, of the underlying layer, at a location of a thermocompression bonding for the electrical interconnection. This enables a reliable electrical interconnection between the leading electrode and the electrode of the interconnection object, thereby allowing a good display performance of each organic EL element to be kept.

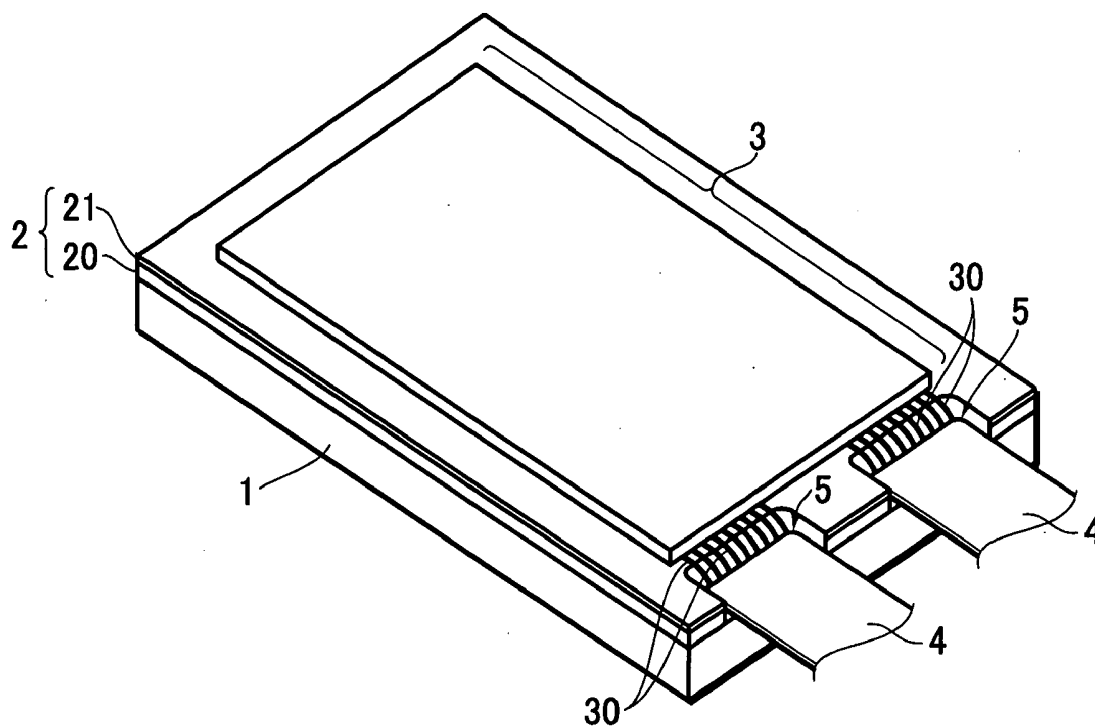


FIG.1

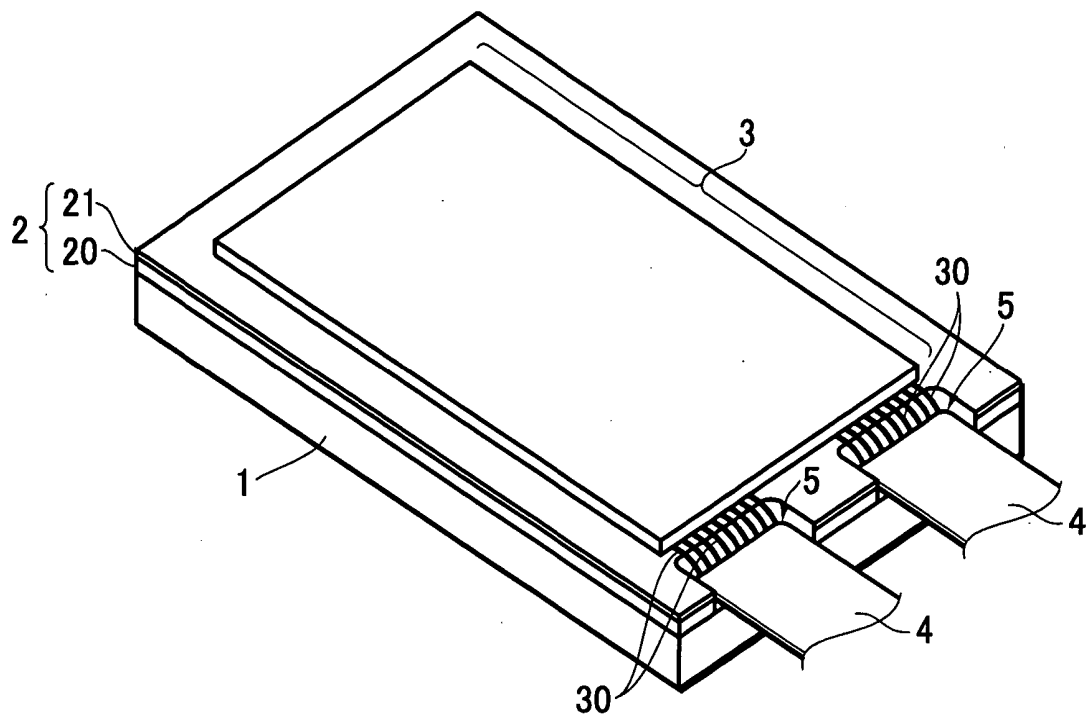


FIG.2

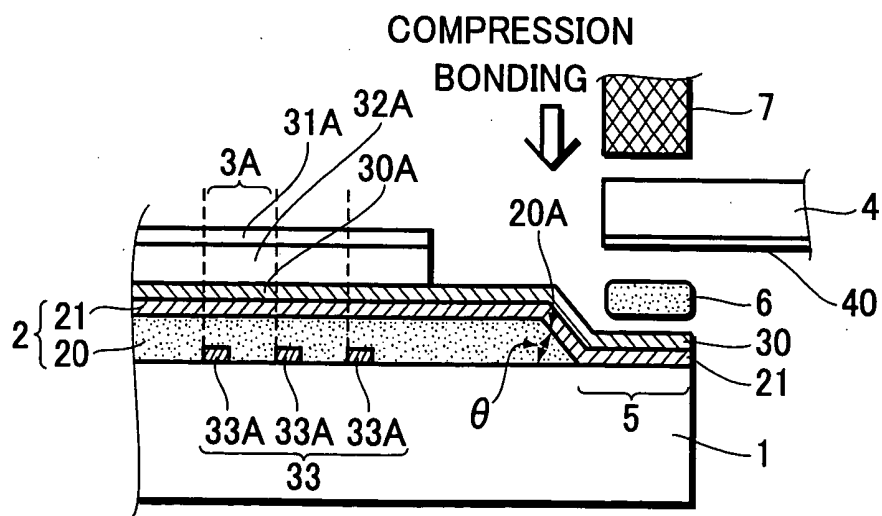


FIG.5

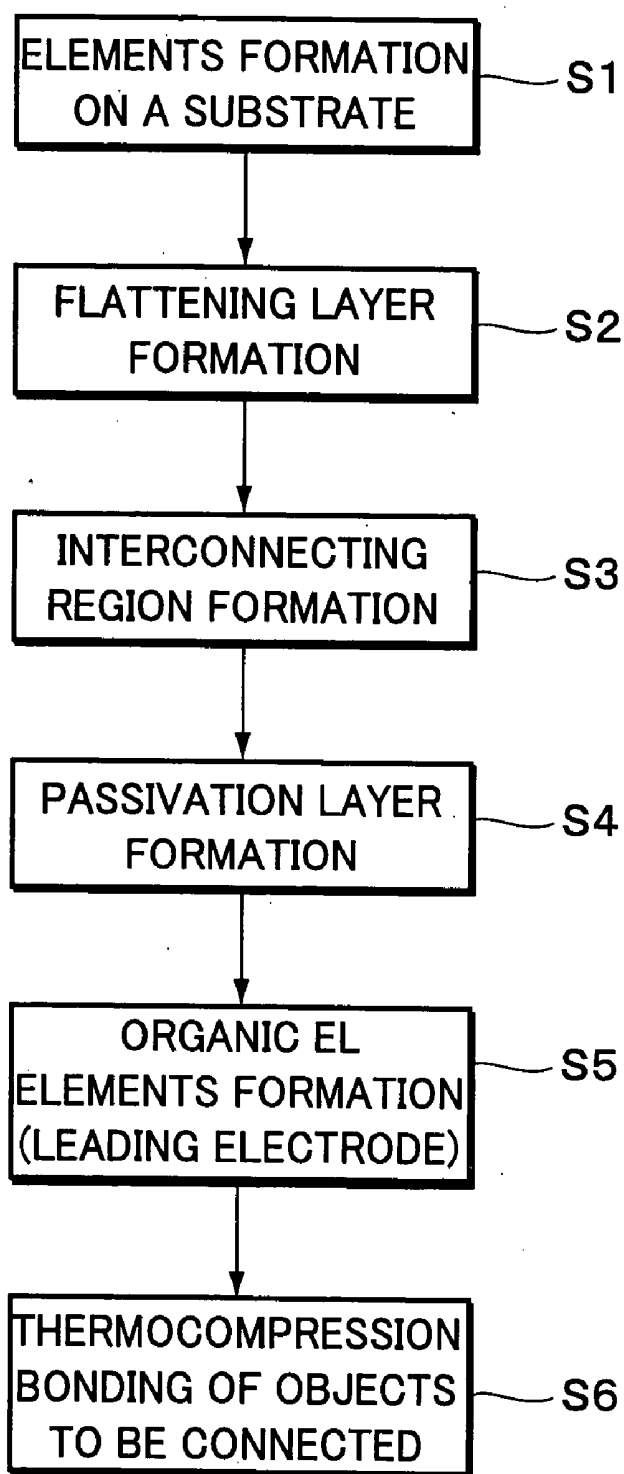


FIG.6 A

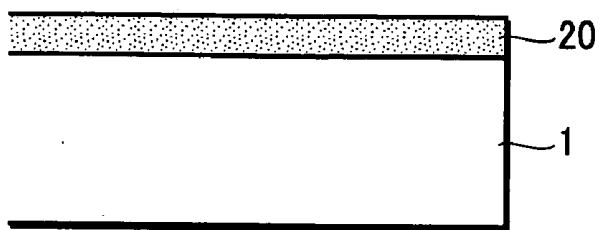


FIG.6 B

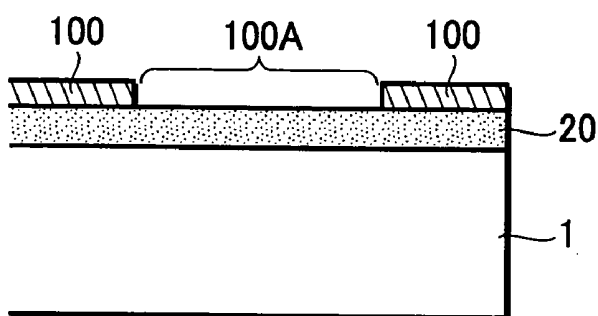


FIG.6 C

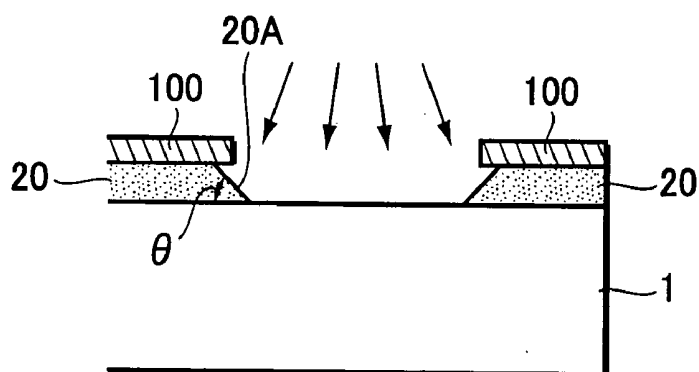
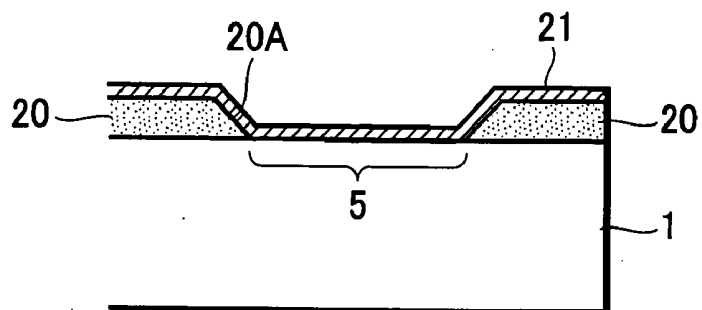


FIG.6 D



ORGANIC EL DISPLAY DEVICE AND METHOD FOR MANUFACTURING THE SAME

BACKGROUND OF THE INVENTION

[0001] The present invention relates to an organic EL (electro-luminescence) display device and a method for manufacturing the same.

[0002] The present application claims priority from Japanese Application No. 2002-323552, the disclosure of which is incorporated herein by reference.

[0003] An organic EL display device shows images on an arrangement of organic EL elements, each of which works as a unit of a light-emitting element. Each organic EL element is constructed as follows; a transparent electrode of ITO or the like is formed to serve as an anode on a transparent glass substrate or the like, on which organic layers including a light-emitting layer are formed of organic compounds, furthermore on which a metallic electrode of Al or the like is formed as a cathode.

[0004] In such an organic EL display device, each functional element such as a Thin Film Transistor (hereinafter referred to as TFT) necessary for active-matrix driving or a color filter or the like for multi-color display is firstly formed on the substrate. In order to flatten an irregular (concavo-convex) surface resulting from the formation of these functional elements, an underlying layer is then formed on the entire substrate, on which each organic EL element is further formed at the location corresponding to that of an individual functional element.

[0005] A specific example of a conventional organic EL display device is disclosed, for example, in Japanese Patent Application Laid-Open No. 2001-356711, in which TFTs are formed on a substrate serving as the above-mentioned functional elements for driving individually the organic EL elements formed in a dot-matrix arrangement. The formation of TFTs and wiring layers connected to them cause the concavo-convex surface, hence a flattening layer of resin material or the like becomes necessary in order to flatten the concavo-convex surface. Furthermore, because gas components, such as moisture, emitting from the flattening layer are possible to deteriorate the organic EL element, a passivation layer is formed as a gas-barrier to prevent its deterioration, on the flattening layer. The organic EL elements, furthermore, are formed on the passivation layer.

[0006] In another conventional example, Japanese Patent Application Laid-Open No. Hei. 11-121164 discloses that color filters or color-converting filters for multi-color display are formed for serving as the above-mentioned functional elements on a substrate. Furthermore, multi-layered flattening layers of resin materials are formed in order to fill and flatten the concavo-convex surface resulting from the formation of the color filters or the color-converting filters. A passivation layer is further provided on the flattening layer, and then the organic EL elements are formed on the passivation layer.

[0007] Such an organic EL display device typically provides the underlying layer including the flattening layer or the passivation layer on the entire surface of the substrate. A simple matrix-driving display device, for example, has connecting regions on the peripheral region of the substrate, for connecting leading electrodes of each organic EL element

with electrodes of peripheral circuits or driving ICs. At each connecting region, the leading electrode drawn out on the above-mentioned underlying layer is interconnected to a Chip On Flexible Printed Circuit (COF) or the like.

[0008] The COF is equipped with the driving ICs on a Flexible Printed Circuit (FPC), and a Tape Carrier Package (TCP) equipped with the IC chips by using a Tape Automated Bonding (TAB) is typically adopted. The interconnection of the TCP electrode and the leading electrode is made by thermocompression bonding of these electrodes sandwiching an anisotropic conductive film (ACF) between them. It is known that failure in the interconnection tends to occur when the leading electrode is formed on the underlying layer of organic materials such as resin or the like. This is because the underlying layer can no longer perform as a supporting base for the leading electrode due to a thermo-deterioration of the underlying layer caused by heating at the thermocompression bonding, hence the thermocompression bonding of the electrodes with the anisotropic conductive film therebetween can not be done sufficiently. More specifically, it is necessary to form at least one layer, which is formed of organic materials, in the underlying layer for flattening the concavo-convex surface on the substrate. However, because a heat-resistance critical temperature of the organic materials is substantially equal to the temperature (180° C.-200° C.) of the thermocompression bonding, the heat-deterioration of the underlying layer is inevitable as a result thereof. A reliable connection is thus hard for the thermocompression bonding of the leading electrodes on the underlying layer.

[0009] This problem is not restricted only to the connection to the COF, but the similar problems occur also in the case of the Chip On Glass (COG) equipped with the IC chips to leading electrodes above a substrate. That is, the COG employs a thermocompression bonding of an electrode of an IC chip and a leading electrode, sandwiching an anisotropic conductive film (ACF) between the two electrodes. When the bonding is performed to the leading electrode formed on the underlying layer, the heat-deterioration of the underlying layer is inevitable, so that a reliable connection may fail.

SUMMARY OF THE INVENTION

[0010] The present invention aims to cope with these problems, that is, the main object of the present invention is to provide a reliable electrical interconnection between leading electrodes of organic EL elements and objects to be interconnected (hereinafter referred to as interconnection objects), in the case of an organic EL display device or the manufacturing method of forming organic EL elements on an underlying layer formed on a substrate. In other words, the objects of the present invention are to achieve an excellent display performance of organic EL elements by the reliable interconnection between the electrodes.

[0011] In order to achieve these objects, a first aspect of the present invention is characterized by an organic EL display device comprising: a substrate; an underlying layer formed on the substrate, the underlying layer including at least one layer formed of organic materials; organic EL elements formed on the underlying layer; leading electrodes drawn out from the organic EL element for electrically connecting with an electrode of an interconnection object on the substrate; and connecting regions formed by removing at

least one layer composing the underlying layer at a location corresponding to a location of thermocompression bonding for electrically connecting the leading electrode with the electrode of the interconnection object.

[0012] A second aspect of the present invention is characterized by a method for manufacturing an organic EL display device comprising the steps of: providing underlying layer formed on a substrate, the underlying layer including at least one layer formed of organic materials; forming interconnection regions by partially removing at least one layer including organic materials in the underlying layer; forming organic EL elements on the underlying layer; forming leading electrodes drawn out from the organic EL elements on the interconnection regions; and performing a thermocompression bonding between the each leading electrode and an electrode of an interconnection object, sandwiching an anisotropic conductive film between these two electrodes on the interconnection region.

BRIEF DESCRIPTION OF THE DRAWINGS

[0013] These and other objects and advantages of the present invention will become clear from the following description with reference to the accompanying drawings, wherein:

[0014] **FIG. 1** is an external view for illustrating a whole structure of an organic EL display device according to an embodiment of the present invention;

[0015] **FIG. 2** is an explanatory view for illustrating a main part of an organic EL display device and a method for manufacturing an organic EL display device according to an embodiment of the present invention;

[0016] **FIG. 3** is a cross sectional view of an example of an organic EL display device driven by an active-matrix according to an embodiment of the present invention;

[0017] **FIG. 4** is a cross sectional view of an example of an organic EL display device driven by a passive-matrix according to an embodiment of the present invention;

[0018] **FIG. 5** is a flowchart for explaining a method for manufacturing an organic EL display device according to an embodiment of the present invention; and

[0019] **FIGS. 6A to 6D** are explanatory views for illustrating a method for manufacture (steps of forming an interconnection region are mainly shown) of an organic EL display device according to an embodiment of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

[0020] Some embodiments of the present invention will be explained referring to drawings. **FIG. 1** is an external view illustrating a whole structure of an organic EL display device according to an embodiment of the present invention. **FIG. 2** is an explanatory view for illustrating a main part of an organic EL display device and a method for manufacturing an organic EL display device according to an embodiment of the present invention.

[0021] In these drawings, embodiments of the present invention will be described on the assumption of an organic EL display device, in which an underlying layer **2** including

at least one layer formed of organic materials is formed on a substrate **1** such as a transparent glass substrate, each organic EL element **3A** (an individual element in an organic EL element area **3**) is formed on the underlying layer **2**, and each electrode of an interconnection object **4** is electrically interconnected to each leading electrode **30** from the organic EL elements **3A**.

[0022] Each organic EL element **3A** in the organic EL element area **3** composes an organic light-emitting functional layer **32A** including light-emitting layers, which is formed between one electrode **30A** (e.g. a transparent electrode of ITO or the like) connected to a leading electrode **30** and the other electrode **31A** (e.g. a metallic electrode such as Al electrode). The interconnection object **4** is not restricted, but may be the above-mentioned TCP (TAB) used in a Chip On FPC (COF), an IC chip used in a Chip On Glass (COG), or a non-flexible circuit board used in a Chip On Board (COB).

[0023] A first embodiment of the present invention is characterized by the formation of each connecting region **5** by removing a layer included in an underlying layer **2**, which is formed of organic materials, corresponding to region of a thermocompression bonding between each leading electrode **30** and an electrode of the interconnection object **4**. In a view of the manufacturing method, provided is a method for manufacturing an organic EL display device comprising the steps of providing an underlying layer **2** composed of a plurality of layers, at least one layer of which is formed of organic materials on a substrate **1**, forming interconnection regions **5** by partially removing a layer formed of organic materials in the underlying layer **2**, forming organic EL elements **3A** on the underlying layer **2**, forming leading electrodes **30** extended from the organic EL elements **3A** on the interconnected regions **5**, and performing the thermocompression bonding of each leading electrode **30** and each electrode **40** of an interconnection object **4** at the interconnected region **5**, lying an anisotropic conductive film **6** between these two electrodes, with a thermocompression bonding tool **7** (a heater tool or the like).

[0024] According to such an embodiment, the connecting regions **5** are formed by partially removing only the layer which is formed of organic materials of the underlying layer **2**, at the location where the thermocompression bonding is performed. Each leading electrode **30** is located at each connecting region **5**, and the thermocompression bonding of the both leading electrode **30** and electrode of the interconnection object **4** lying an anisotropic conductive film **6** between the two electrodes is performed with the thermocompression bonding tool **7**. In this structure, the layer of organic materials hindering the thermocompression bonding does not exist under the location of the thermocompression bonding, and thus the anisotropic conductive film **6** is sufficiently compressed between the leading electrode **30** and the electrode **40** of the interconnection object **4**, so that a reliable electric connection between the leading electrode **30** and the electrode **40** can be accomplished.

[0025] A second embodiment of the present invention presupposing the first embodiment is characterized in that an underlying layer removal surface **20A** facing to the connecting region **5** is an upward tapered surface inclined to the substrate **1** within the angle range $\theta=45^\circ\pm30^\circ$.

[0026] This embodiment enables a further formation of new layers on the underlying layer removal surface **20A**,

because the surface is an upward tapered surface. Thus, another layer (a passivation layer **21**) or the leading electrode **30** can be formed continuously on the underlying layer removal surface **20A** as shown in **FIG. 2**.

[0027] The range of the inclination angle θ of the underlying layer removal surface **20A** will be explained as follows. If the inclination angle θ is less than the maximum angle 75° , the new layer can be formed thereon without any separation and with a sufficient thickness for fulfilling its functions. The leading electrode **30**, for instance, results in a high-resistance when a layer thereof becomes thin in thickness even if not separated, so that this negatively affects the performance of light emission of an organic EL element. In addition, the minimum angle 15° indicates a limit that the tapered-surface can be practically formed.

[0028] A third embodiment of the present invention presupposing the abovementioned embodiments is characterized in that the underlying layer **2** provides the passivation layer **21** serving as a gas-barrier formed at a top layer of the underlying layer **2**.

[0029] Such a formation of the passivation layer **21** serving as a gas-barrier at the top of the underlying layer **2** containing at least one layer of organic materials, is able to confine gas components such as moisture emitted from organic materials. Thereby, deterioration, which is caused from these gases, in the leading electrode **30** or the organic light-emitting functional layer of the organic EL element **3A** can be prevented. When the underlying layer removal surface **20A** is formed with its tapered surface within the abovementioned angles, a separation of the passivation layer **21** formed thereon can be avoided. When the underlying layer **2** is also removed partially to form an connecting region **5**, the passivation layer **21** completely covers the underlying layer **2** including organic materials on an entire substrate thereof, thereby allowing an excellent display performance of the organic EL element **3A** to be kept. At the connecting region **5** where the layer of organic materials is removed, the passivation layer **21** may be alternatively removed within the limit of not exposing organic layers. Moreover, this embodiment is not shown in the drawings.

[0030] A forth embodiment is characterized in that the underlying layer **2** involves a flattening layer **20** to flatten the concavo-convex surface due to functional elements **33** formed on the substrate **1**. A fifth embodiment is characterized in that the functional element **33** is composed of each individual functional element **33A** corresponding to every organic EL element **3A**, and the functional element **33A** may be a thin film transistor (TFT). A sixth embodiment is characterized in that the functional element **33A** may be a color-converting filter or a color filter.

[0031] According to these characteristics, the organic EL elements can be formed on a flattened layer, because the flattening layer **20** is capable of flattening the concavo-convex surface due to functional elements **33**, whether large or small. Thus, the control in film thickness of elements with a high precision allows high-quality elements to be formed. The abovementioned characteristics can be always obtained, even if the functional elements are TFTs, color-converting filters, or color filters. Thus, regardless of a kind of driving method such as active or passive-matrix or the number of display colors such as mono-color or multi-color, the thermocompression bonding at the connecting region of the

leading electrode can be performed in the stable and good quality. Consequently, the organic EL display devices and the same manufacturing method can be supplied with the abovementioned characteristics.

Examples of Embodiment

[0032] The embodiments of the present invention will be explained referring to drawings. **FIG. 3** is a drawing for illustrating an example of an organic EL display device driven by an active-matrix according to an embodiment of the present invention. In this organic EL display device, each TFT **8** is formed every organic EL element **3B** composing a pixel on a substrate **1** such as transparent glass substrate, and wiring (gate wiring, drain wiring, not shown in **FIG. 3**) formed on the substrate **1** are connected to each TFT **8**. Furthermore, a flattening layer **20** having an underlying layer removal surface **20A** at a connecting region **5** is formed on the substrate **1**, and a passivation layer **21** is formed for covering the flattening layer **20**.

[0033] The flattening layer **20** is formed of resin materials such as acryl or polyimide, or organic materials such as organic silica or the like, using application methods such as spin-coating, dip-coating, or slot-coating. The flattening layer **20** is formed to fill and cover the concavo-convex surface resulting from TFTs **8** or wiring on the substrate **1**, serving as a flat base for formation of organic EL elements **3B**. The passivation layer **21** is formed of insulated materials involving inorganic materials such as silicon oxide, silicon nitride, or amorphous silicon, for working as a gas barrier which intercept gases (moisture or the like) emitted from the flattening layer **20**, by using a film formation method such as ion plating, sputtering, low-temperature sputtering, evaporation, or EB.

[0034] The organic EL elements **3B** are formed on the passivation layer **21** which is formed at the top layer of the underlying layer **2** including the flattening layer **20**. In this embodiment, the organic EL element **3B** has a structure of emitting light to the substrate **1**. That is, a pixel electrode **30B** is formed of transparent materials such as ITO or the like, as an anode on the underlying layer **2**, on which an organic light-emitting functional layer **32B** including, for instance, a hole injection layer, a hole transport layer, a light-emitting layer, an electron transport layer, and an electron injection layer, is formed. Furthermore, a common metallic electrode **31B** is formed as a cathode thereon. An insulating layer **81** is formed for separating each pixel electrode **30B** and an organic light-emitting functional layer **32B** from adjacent pixel electrodes and adjacent organic light-emitting functional layers **32B**, respectively. A structure of emitting light to a substrate is shown here as an example, but a structure of emitting light to a reverse (upward) direction may be formed by reversing the formation order of the organic light-emitting functional layers and also the order of the upper and lower electrodes.

[0035] The connecting region **5** is formed at a periphery of a substrate **1** by partially removing the flattening layer **20** formed of organic materials. The underlying layer removal surface **20A** is an upward tapered plane adjacent to the connecting region **5**, which is formed when removing the flattening layer. The whole surface of connecting region **5** including the flattening layer removal surface **20A** is covered with the passivation layer **21**, on which each leading

electrode **30** connected to the above-mentioned pixel electrode **30B** is formed. Thus, at the connecting region **5**, a region without the flattening layer **20** formed of organic materials serves as a compression bonding region, in which a thermocompression bonding is performed between the leading electrode **30** and an electrode **40** of an interconnection object **4** (e.g. TCP (TAB)) sandwiching an anisotropic conductive film **6** therebetween.

[0036] FIG. 4 is an explanatory view of an organic EL display device driven by a passive-matrix according to another embodiment of the present invention. In this figure, each part which is common to that of the abovementioned embodiment will be denoted by the same symbol, and the explanation for the common parts will be omitted. In the organic EL display device, each color converting filter or color filter **9A**, **9B**, **9C**, for multi-color display is formed corresponding to every organic EL element **3C** serving as a pixel, on a substrate **1** such as transparent glass or the like. Furthermore, on the substrate **1** is formed a flattening layer **20** having an underlying layer removal surface **20A** facing to a connecting region **5**, on which a passivation layer **21** is formed to cover the flattening layer **20**.

[0037] Each organic EL element **3C** is formed on the underlying layer **2** including the flattening layer **20** and the passivation layer **21**. In this embodiment, the organic EL element **3C** emits light to the substrate **1**. That is, lower electrodes **30C** are formed of transparent materials such as ITO or the like with striped pattern serving as an anode on the underlying layer **2**, on which an organic light-emitting functional layer **32C** including, for instance, a hole injection layer, a hole transport layer, a light-emitting layer, an electron transport layer, and an electron injection layer, is formed. Then, on the organic light-emitting functional layer **32C**, upper electrodes **31C** (metallic electrode such as Al or the like) are formed with a striped pattern crossing with the lower electrodes **30C**. A structure of emitting light in a direction to a substrate **1** is shown here as an example, but a structure of emitting light in the reverse (upward) direction may be also formed by reversing the order of an organic light-emitting functional layers and also the order of the upper and lower electrodes.

[0038] Similarly to the first embodiment, the connecting region **5** is formed at the periphery of the substrate **1** by partial removal of the flattening layer **20** formed of organic materials. The underlying layer removal surface **20A** is formed with an upward tapered plane facing to the connecting region **5**, after removing the flattening layer **20**. The whole surface of connecting region **5** including the flattening layer removal surface **20A** is covered with the passivation layer **21**, on which a leading electrode **31** connected to the abovementioned upper electrode **31C** is formed. Thus, in this embodiment also, a region with the flattening layer **20** removed also serves as a compression bonding region at the connecting region **5**, in which a thermocompression bonding is performed between the leading electrode **31** and an electrode **40** of an interconnection object **4** (e.g. TCP (TAB)) sandwiching an anisotropic conductive film **6** therebetween.

[0039] Next, a method for manufacturing such organic EL display devices will be explained referring to the flowchart illustrated in FIG. 5. First, at the step S1, each element such as TFT **8**, color converting filter or color filter **9A**, **9B**, and

9C is formed to serve as an active-matrix driving, or a functional element for multi-color display, on the substrate **1**.

[0040] At the step S2, the abovementioned flattening layer **20** is formed by a coating method such as a spin-coating on the entire substrate **1** in which the abovementioned elements have been formed on the substrate **1**. Then, at the step S3, each connecting region **5** is formed by removing the flattening layer **20**, at the location of the thermocompression bonding to the interconnection object **4**. At the step S4, the passivation layer **21** is formed on the upper surface of the flattening layer **20** and also the substrate in the connecting region **5**.

[0041] More detailed description will be given with regard to the process (step 3) of forming the connecting region and the process (step 4) of forming the passivation layer, referring to FIG. 6. First, the flattening layer **20** is formed on the substrate **1** by using the abovementioned coating method, as shown in FIG. 6A. Next, a resist layer **100**, which has openings **100A** formed by using lithography technique or the like at the location of the connecting regions **5**, is formed on the flattening layer **20**.

[0042] The flattening layer **20** under the opening **100A** is removed by using developing process. Under this removal situation, the developing fluid enters into the underside of the resist layer **100** near an edge thereof, so that the underlying layer removal surface **20A** is formed in a tapered shape, as shown in FIG. 6C. Therefore, it becomes possible to adjust an inclination angle θ of the tapered surface, by controlling the duration-time of developing process.

[0043] The setting of the inclination angle θ of the tapered surface (underlying layer removal surface **20A**) is an important factor for obtaining excellent performances in the organic EL display device. In this embodiment, it has been confirmed that the inclination angle θ is effective in the range from 15° to 75° ($\theta=45^\circ\pm30^\circ$). That is, when the angle is smaller than 15° , it is difficult to form the tapered surface itself, and it is also impossible to utilize the substrate effectively, because of the formation of the wider tapered surface near the connecting region. On the other hand, when the angle is larger than 75° near a right angle, the respective separation in the passivation layer and the leading electrode formed on the tapered surface may be suffered, and it may be also difficult to obtain the sufficient thickness capable of serving as the passivation layer or the leading electrode. Therefore, the setting of the inclination angle θ ranging $45^\circ\pm30^\circ$ results in an excellent performance of the organic EL display device because any separation of the leading electrode or the passivation layer can be avoided.

[0044] Following these processes, the resist layer is removed, and a passivation layer **21** is formed on both the flattening layer **20** and the substrate **1** at the connecting region **5**, as shown in FIG. 6D. At the step S5 in FIG. 5, the organic EL element (**3A**, **3B**, or **3C**) is formed on the underlying layer **2** including the flattening layer **20** and the passivation layer **21**, and the leading electrode (**30**, **31**) is formed at the location of the connecting region **5**. At the step S6, the thermocompression bonding is performed to connect the leading electrode with the interconnection object **4** at the connecting region **5** where the flattening layer **20** is removed.

[0045] In the organic EL display device and its manufacturing method according to the above-mentioned embodi-

ments, the connecting region **5** is formed by partially removing the flattening layer **20** formed of organic materials at the location of the thermocompression bonding. Then, at the connecting region **5**, the thermocompression bonding is performed between the leading electrode (**30, 31**) from the organic EL element (**3A, 3B, 3C**) and the electrode **40** of the interconnection object **4**, sandwiching the isotropic conductive film **6** therebetween. Owing to the absence of layers formed of organic materials, which hinder the thermocompression bonding beneath the location of connecting region, the isotropic conductive film **6**, which is sandwiched between the leading electrode (**30, 31**) from an organic EL element (**3A, 3B, 3C**) and the electrode **40** of the interconnection object **4**, is able to be pressed sufficiently. Therefore, a reliable electric connection between the leading electrode (**30, 31**) and the electrode **40** can be achieved.

[0046] Because the underlying layer removal surface **20A** has an upward tapered surface, on which layers can be formed thereon by deposition. When the inclination angle θ of the tapered surface is set in the range of $\theta=45^\circ\pm 30^\circ$, the passivation layer **21** or the leading electrode **30** can be formed on the flattening layer **20** without separation or cutting on the tapered surface, so that the organic EL element (**3A, 3B, 3C**) can retain a good display performance.

[0047] Although the embodiments described above show an example of forming the passivation layer on the connecting region **5**, the surface of the substrate **1** may be exposed by removing the passivation layer **21** if the flattening layer is not exposed.

[0048] While there has been described what are at present considered to be preferred embodiments of the present invention, it will be understood that various modifications may be made thereto, and it is intended that the appended claims cover all such modifications as fall within the true spirit and scope of the invention.

What is claimed is:

1. An organic EL display device comprising:
 - a substrate;
 - an underlying layer formed on said substrate, said underlying layer including at least one layer formed of organic materials;
 - organic EL elements formed on said underlying layer;
 - leading electrodes drawn out from said organic EL element for electrically connecting with an electrode of an interconnection object on said substrate; and
 - connecting regions formed by removing at least one layer composing said underlying layer at a location corresponding to a location of thermocompression bonding for electrically connecting said leading electrode with said electrode of the interconnection object.
2. The organic EL display device according to claim 1, wherein said connecting regions are formed by removing said at least one layer formed of organic materials in said underlying layer.

3. The organic EL display device according to claim 1, wherein regions for removing said one layer of the underlying layer adjacent to the connecting regions have an upward tapered surface inclined to the substrate within an angle range of $45^\circ\pm 30^\circ$, respectively.

4. The organic EL display device according to claim 1, wherein the underlying layer includes a passivation layer serving as a gas-barrier formed at a top layer thereof.

5. The organic EL display device according to claim 1, wherein the underlying layer includes at least a flattening layer to flatten a concavo-convex surface caused by functional elements provided on the substrate.

6. The organic EL display device according to claim 5, wherein the functional element is a thin film transistor provided every said organic EL element.

7. The organic EL display device according to claim 5, wherein said functional element is a color converting filter or a color filter provided every said organic EL element.

8. A method for manufacturing an organic EL display device comprising the steps of:

providing underlying layer formed on a substrate, said underlying layer including at least one layer formed of organic materials;

forming interconnection regions by partially removing at least one layer including organic materials in said underlying layer;

forming organic EL elements on said underlying layer;

forming leading electrodes drawn out from said organic EL elements on said interconnection regions; and

performing a thermocompression bonding between said each leading electrode and an electrode of an interconnection object, sandwiching an anisotropic conductive film between these two electrodes on the interconnection region.

9. The method according to claim 8, wherein regions for removing said one layer of the underlying layer adjacent to the connecting regions have an upward tapered surface inclined to the substrate within an angle range of $45^\circ\pm 30^\circ$, respectively.

10. The method according to claim 8, wherein the underlying layer includes a passivation layer serving as a gas-barrier formed at a top layer thereof.

11. The method according to claim 8, wherein the underlying layer includes at least a flattening layer to flatten a concavo-convex surface caused by functional elements provided on the substrate.

12. The method according to claim 11, wherein said functional element is a thin film transistor provided every said organic EL element.

13. The method according to claim 11, wherein said functional element is a color converting filter or a color filter provided every said organic EL element.

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专利名称(译)	有机EL显示装置及其制造方法		
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摘要(译)

提供一种有机EL显示装置，包括：底层，包括形成在基板上的至少一个由有机材料形成的层；在其上形成有机EL元件；来自有机EL元件的每个引导电极用于电互连到互连物体的电极。在显示装置中，每个连接区域通过在用于电互连的热压接合的位置处去除由下层的有机材料形成的层而形成。这使得能够在引导电极和互连物体的电极之间进行可靠的电互连，从而允许保持每个有机EL元件的良好显示性能。

